



# 56Gb/s PAM4 (28GBd) 850nm Multimode Dual Top Contact VCSEL Array VCCx-85A56G

Data Sheet



## Description

The Lasermate VCCx-85A56G is an 850nm wavelength, Vertical Cavity Surface Emitting Laser (VCSEL) chip and chip array available with up to 12 channels. The VCSEL is designed for use in 56Gbps PAM4 application.

## Features

- 850nm multimode emission
- 1xN array bar with 250um pitch
- High data rate up to 56 Gbps PAM4
- P and N bonding pads on top surface
- Low threshold and operation current

## Applications

- High speed Data communications
- Gigabit ethernet
- Fiber channel

## Product Overview

Part Number	Package
VCCA2-85A56G	1x2 Array
VCCA4-85A56G	1x4 Array
VCCA8-85A56G	1x8 Array
VCCA12-85A56G	1x12 Array

## Specifications

Absolute Maximum Ratings				
Parameters	Min.	Max.	Unit	Conditions
Storage Temperature	-40	100	°C	
Operating Temperature	-10	85	°C	
Maximum Operating Current		10	mA	
Continuous Reverse Voltage		5	V	

Electro-Optical Characteristics						
Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions
Threshold Current	$I_{th}$		0.55		mA	
Slope Efficiency	$\eta$		0.6		mW/mA	$I_F=7mA$
Output Power	$P_o$		3.8		mW	$I_F=7mA$
Wavelength	$\lambda_P$	840		860	nm	$I_F=7mA$
Forward Voltage	$V_F$		1.9	2.3	V	$I_F=7mA$
Series Resistance	$R_s$		60	85	$\Omega$	$I_F=7mA$
Spectral Width (RMS)	$\Delta\lambda$		0.3		nm	$I_F=7mA$
Beam Divergence	$\Theta$		28	33	degree	$I_F=7mA (1/e^2)$
3dB Bandwidth	BW		20		GHz	$I_F=7mA$
Relative Intensity Noise	RIN		-140	-135	dB/Hz	$I_F=7mA, T=25^\circ C$

Note: All parameters except mentioned are measured at  $I_F=7mA$ ,  $25^\circ C$ , CW operation.

## Typical Characteristics

Fig. 1 Typical Optical Characteristics

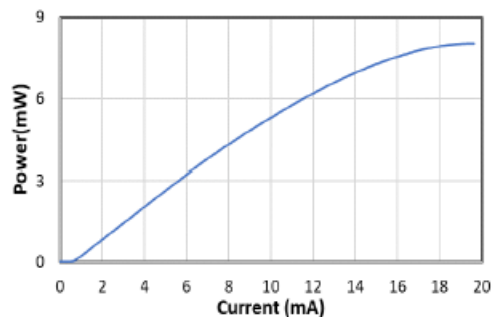


Fig. 2 Typical Electrical Characteristics

